TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SG32FU

2 Input OR Gate

Features

• High-level output current: $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$

at V_{CC} = 3.0 V

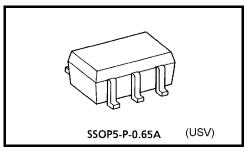
• High-speed operation: t_{pd} = 2.4 ns (typ.)

at $V_{CC} = 3.3 \text{ V}, 15 \text{pF}$

Operating voltage range: V_{CC} = 0.9~3.6 V

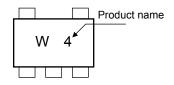
• 5.5-V tolerant inputs.

• 3.6-V power down protection output.

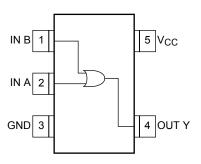


Weight: 0.006 g (typ.)

Marking



Pin Assignment (top view)



Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit	
Power supply voltage	V _{CC}	-0.5~4.6	V	
DC input voltage	V _{IN}	-0.5~7.0	٧	
DC output voltage	\/	-0.5~ 4.6 (Note 1)		
	Vout	-0.5~ V _{CC} + 0.5 (Note 2)	V	
Input diode current	l _{IK}	-20	mA	
Output diode current	lok	-20 (Note 3)	mA	
DC output current	lout	±25	mA	
DC V _{CC} /ground current	Icc	±50	mA	
Power dissipation	PD	200	mW	
Storage temperature	T _{stg}	-65~150	°C	

Note:

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

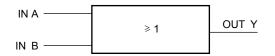
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: V_{CC} = 0V

Note 2: High or Low State. IOUT abusolute maximum rating must be observed.

Note 3: V_{OUT} < GND

IEC Logic Symbol



Truth Table

Α	В	Υ
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

Operating Ranges

Characteristics	Symbol	Value	Unit	
Power supply voltage	V _{CC}	0.9~3.6	V	
Input voltage	V _{IN}	0~5.5	V	
Output voltage	V	0~3.6 (Note 4)	- V	
	V _{OUT}	0~V _{CC} (Note 5)		
Output Current		±8.0 (Note 6)		
	I _{OH} /I _{OL}	±4.0 (Note 7)		
		±3.0 (Note 8)	mA	
		±1.7 (Note 9)		
		±0.3 (Note 10)		
		±0.02 (Note 11)		
Operating temperature	T _{opr}	−40~85	°C	
Input rise and fall time	dt/dV	0~10 (Note 12)	ns/V	

Note 4: $V_{CC} = 0V$

Note 5: High or Low state.

Note 6: V_{CC} = 3.0~3.6 V

Note 7: $V_{CC} = 2.3 \sim 2.7 \text{ V}$

Note 8: $V_{CC} = 1.65 \sim 1.95 \text{ V}$

Note 9: $V_{CC} = 1.4 \sim 1.6 \text{ V}$

Note 10: V_{CC} = 1.1~1.3 V

Note 11: $V_{CC} = 0.9 V$

Note 12: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

DC Electrical Characteristics

Characteristics Symbol		Test Condition Vo			Ta = 25°C			Ta = -40~85°C		11.2
				V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
High-level VIH input voltage				0.9	V_{CC}	_	_	V _C C	_	
				1.1~1.3	V _{CC} × 0.7	_	_	V _{CC} × 0.7	_	
	V _{IH}	_		1.4~1.6	V _{CC} × 0.65	_	_	V _{CC} × 0.65	_	V
			1.65~1.95	V _{CC} × 0.65	_	_	V _{CC} × 0.65			
				1.7	_	_	1.7			
					2.0	_	_	2.0		
				0.9	_	_	GND	_	GND	
Low-level V _{IL}				1.1~1.3	_		V _{CC} × 0.3	_	V _{CC} × 0.3	
		_				V _{CC} × 0.35		V _{CC} × 0.35	٧	
input voltage						١	V _{CC} × 0.35		V _{CC} × 0.35	
					_		0.7		0.7	
				3.0~3.6	_		0.8		0.8	
			I _{OH} =-0.02 mA	0.9	0.75		_	0.75		V
		V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -0.3 \text{ mA}$	1.1~1.3	V _{CC} × 0.75	١	_	V _{CC} × 0.75	١	
High-level V _{OH}	Voh		$I_{OH} = -1.7 \text{ mA}$	1.4~1.6	V _{CC} × 0.75	١	_	V _{CC} × 0.75	١	
			$I_{OH} = -3.0 \text{ mA}$	1.65~ 1.95	V _{CC} -0.45		_	V _{CC} -0.45	l	
			$I_{OH} = -4.0 \text{ mA}$	2.3~2.7	2.0		_	2.0	_	
			$I_{OH} = -8.0 \text{ mA}$	3.0~3.6	2.48	_	—	2.48	_	
		$V_{IN} = V_{IL}$	$I_{OL} = 0.02 \text{ mA}$	0.9	_		0.1	_	0.1	V
			$I_{OL} = 0.3 \text{ mA}$	1.1~1.3	_		V _{CC} × 0.25	_	V _{CC} × 0.25	
Low-level output voltage	V _{OL}		I _{OL} = 1.7 mA	1.4~1.6	_		V _{CC} × 0.25	_	V _{CC} × 0.25	
			I _{OL} = 3.0 mA	1.65~ 1.95	_		0.45	_	0.45	
			I _{OL} = 4.0 mA	2.3~2.7	_	_	0.4	_	0.4	
			I _{OL} = 8.0 mA	3.0~3.6	_		0.4	_	0.4	
Input leakage current	I _{IN}	V _{IN} = 0~5.5V		0~3.6	_		±0.1	_	±1.0	μА
Power off leakage current	I _{OFF}	V _{IN} = 0~5.5V V _{OUT} = 0~3.6V		0	_		1.0	_	10.0	μА
Quiescent supply current	Icc	$V_{IN} = V_{CC}$	or GND	3.6	_	_	1.0	_	10.0	μΑ

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AC Electrical Characteristics (input $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40~85°C		Unit	
Characteristics			C _{L (} pF)	Min	Тур.	Max	Min	Max	Offic
		$C_L = 10 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9	_	17.0	_	_	_	
			1.1~1.3	_	8.8	18.4	1.0	34.2	
			1.4~1.6	_	5.0	8.5	1.0	10.0	
			1.65~ 1.95		3.8	6.2	1.0	6.7	
			2.3~2.7	_	2.7	3.9	1.0	4.4	
			3.0~3.6	_	2.1	3.1	1.0	3.7	
		$C_L=15$ pF, $R_L=1$ M Ω	0.9	_	20.7	_	_	_	
	tpLH tpHL		1.1~1.3	_	10.6	21.5	1.0	37.2	
			1.4~1.6	_	5.9	9.3	1.0	11.2	
Propagation delay time			1.65~ 1.95	_	4.5	6.9	1.0	7.1	ns
			2.3~2.7	_	3.0	4.4	1.0	5.0	
			3.0~3.6	_	2.4	3.4	1.0	3.9	
		$C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9	_	29.6	_	_	_	
			1.1~1.3	_	14.8	29.6	1.0	56.0	
			1.4~1.6	_	8.0	13.1	1.0	15.9	
			1.65~ 1.95	_	6.0	9.2	1.0	9.6	
			2.3~2.7	_	3.9	5.7	1.0	6.1	
			3.0~3.6	_	3.0	4.4	1.0	4.8	
Input capacitance	C _{IN}	_	3.6	_	3	_	_	_	pF
Power dissipation capacitance	C _{PD}	(Note 13)	0.9~3.6	—	6			_	pF

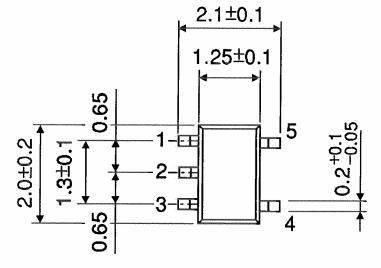
Note 13: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

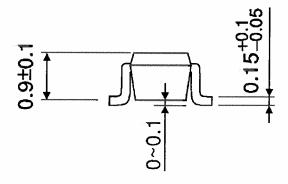
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Package Dimensions

SSOP5-P-0.65A Unit: mm





Weight: 0.006 g (typ.)

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20070701-EN GENERAL

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